

## P-Channel 30-V (D-S) MOSFET

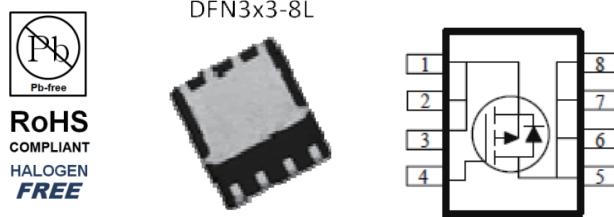
### Key Features:

- Low  $r_{DS(on)}$  trench technology
- Low thermal impedance
- Fast switching speed

### Typical Applications:

- Load Switches
- DC/DC Conversion
- Motor Drives

| PRODUCT SUMMARY |                       |           |
|-----------------|-----------------------|-----------|
| $V_{DS}$ (V)    | $r_{DS(on)}$ (mΩ)     | $I_D$ (A) |
| -30             | 8 @ $V_{GS} = -10V$   | -18       |
|                 | 11 @ $V_{GS} = -4.5V$ | -15       |



### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ C$ UNLESS OTHERWISE NOTED)

| Parameter   | Symbol         | Limit      | Units |
|---|----------------|------------|-------|
| Drain-Source Voltage                                      | $V_{DS}$       | -30        | V     |
| Gate-Source Voltage                                       | $V_{GS}$       | $\pm 20$   |       |
| Continuous Drain Current <sup>a</sup>                     | $I_D$          | -18        | A     |
|   |                | -13        |       |
| Pulsed Drain Current <sup>b</sup>                         | $I_{DM}$       | -50        |       |
| Continuous Source Current (Diode Conduction) <sup>a</sup> | $I_S$          | -4.6       | A     |
| Power Dissipation <sup>a</sup>                            | $P_D$          | 3.5        | W     |
|   |                | 2          |       |
| Operating Junction and Storage Temperature Range          | $T_J, T_{stg}$ | -55 to 150 | °C    |

### THERMAL RESISTANCE RATINGS

| Parameter                                | Symbol          | Maximum | Units |
|--|-----------------|---------|-------|
| Maximum Junction-to-Ambient <sup>a</sup> | $R_{\theta JA}$ | 35      | °C/W  |
|  |                 | 81      |       |

### Notes

- Surface Mounted on 1" x 1" FR4 Board.
- Pulse width limited by maximum junction temperature

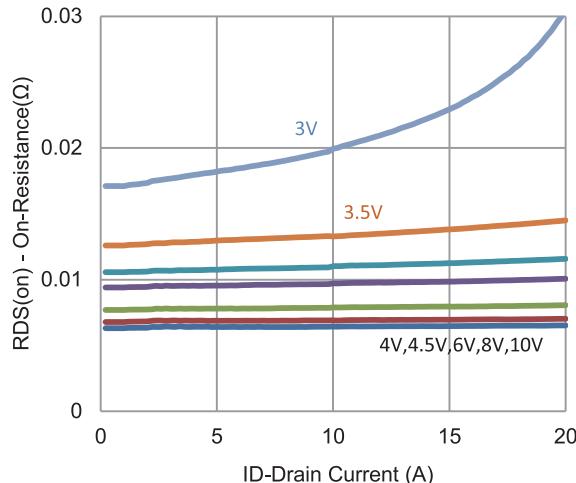
## Electrical Characteristics

| Parameter                               | Symbol       | Test Conditions  | Min | Typ   | Max       | Unit |
|---|--------------|--|-----|-------|-----------|------|
| <b>Static</b>                           |              |  |     |       |           |      |
| Gate-Source Threshold Voltage           | $V_{GS(th)}$ | $V_{DS} = V_{GS}$ , $I_D = -250 \mu A$   | -1  |       |           | V    |
| Gate-Body Leakage                       | $I_{GSS}$    | $V_{DS} = 0 V$ , $V_{GS} = \pm 20 V$   |     |       | $\pm 100$ | nA   |
| Zero Gate Voltage Drain Current         | $I_{DSS}$    | $V_{DS} = -24 V$ , $V_{GS} = 0 V$  |     |       | -1        | uA   |
|   |              | $V_{DS} = -24 V$ , $V_{GS} = 0 V$ , $T_J = 55^\circ C$   |     |       | -25       |      |
| On-State Drain Current <sup>a</sup>     | $I_{D(on)}$  | $V_{DS} = -5 V$ , $V_{GS} = -10 V$   | -25 |       |           | A    |
| Drain-Source On-Resistance <sup>a</sup> | $r_{DS(on)}$ | $V_{GS} = -10 V$ , $I_D = -13.6 A$   |     |       | 8         | mΩ   |
|   |              | $V_{GS} = -4.5 V$ , $I_D = -10.9 A$  |     |       | 11        |      |
| Forward Transconductance <sup>a</sup>   | $g_{fs}$     | $V_{DS} = -15 V$ , $I_D = -13.6 A$   |     | 12    |           | S    |
| Diode Forward Voltage <sup>a</sup>      | $V_{SD}$     | $I_S = -2.3 A$ , $V_{GS} = 0 V$  |     | -0.76 |           | V    |
| <b>Dynamic <sup>b</sup></b>             |              |  |     |       |           |      |
| Total Gate Charge                       | $Q_g$        | $V_{DS} = -15 V$ , $V_{GS} = -4.5 V$ ,<br>$I_D = -13.6 A$  |     | 60    |           | nC   |
| Gate-Source Charge                      | $Q_{gs}$     |  |     | 17    |           |      |
| Gate-Drain Charge                       | $Q_{gd}$     |  |     | 22    |           |      |
| Turn-On Delay Time                      | $t_{d(on)}$  | $V_{DS} = -15 V$ , $R_L = 1.2 \Omega$ ,<br>$I_D = -13.6 A$ ,<br>$V_{GEN} = -10 V$ , $R_{GEN} = 6 \Omega$ |     | 14    |           | ns   |
| Rise Time                               | $t_r$        |  |     | 37    |           |      |
| Turn-Off Delay Time                     | $t_{d(off)}$ |  |     | 124   |           |      |
| Fall Time                               | $t_f$        |  |     | 55    |           |      |
| Input Capacitance                       | $C_{iss}$    | $V_{DS} = -15 V$ , $V_{GS} = 0 V$ , $f = 1 \text{ Mhz}$  |     | 5743  |           | pF   |
| Output Capacitance                      | $C_{oss}$    |  |     | 453   |           |      |
| Reverse Transfer Capacitance            | $C_{rss}$    |  |     | 446   |           |      |

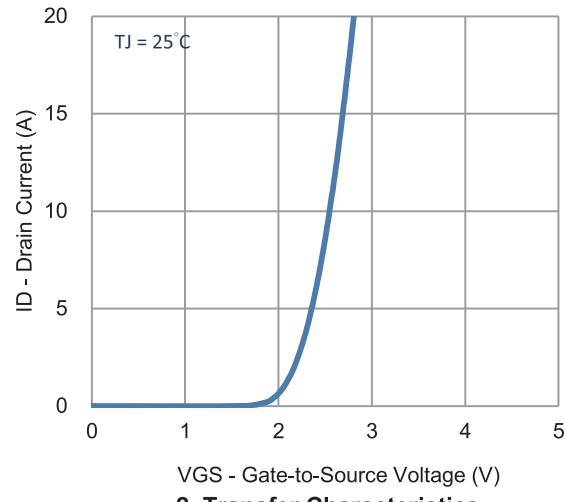
## Notes

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

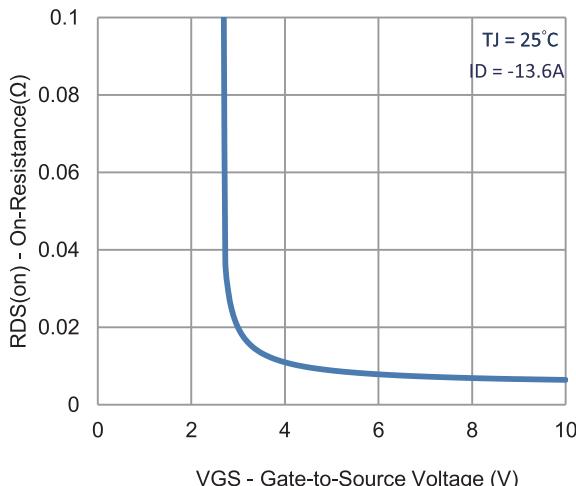
## Typical Electrical Characteristics



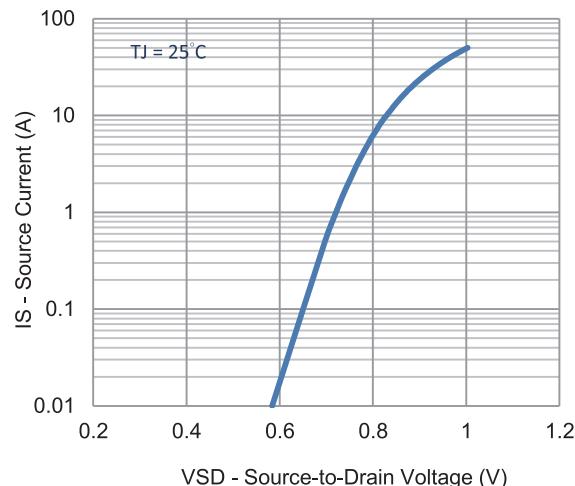
**1. On-Resistance vs. Drain Current**



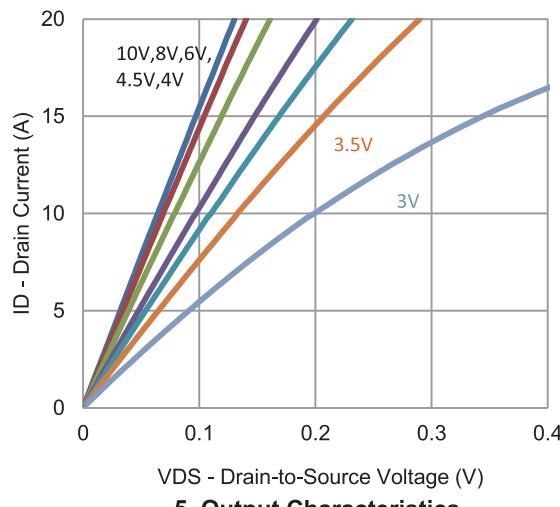
**2. Transfer Characteristics**



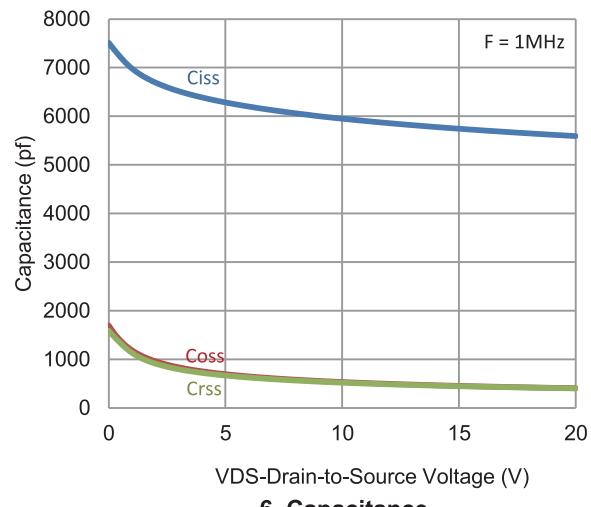
**3. On-Resistance vs. Gate-to-Source Voltage**



**4. Drain-to-Source Forward Voltage**

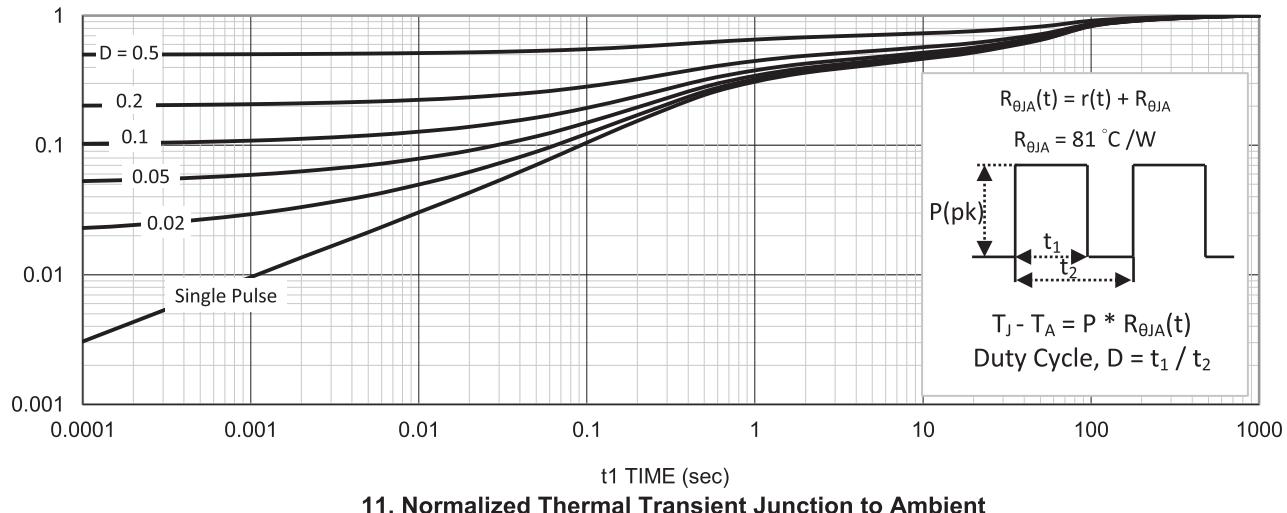
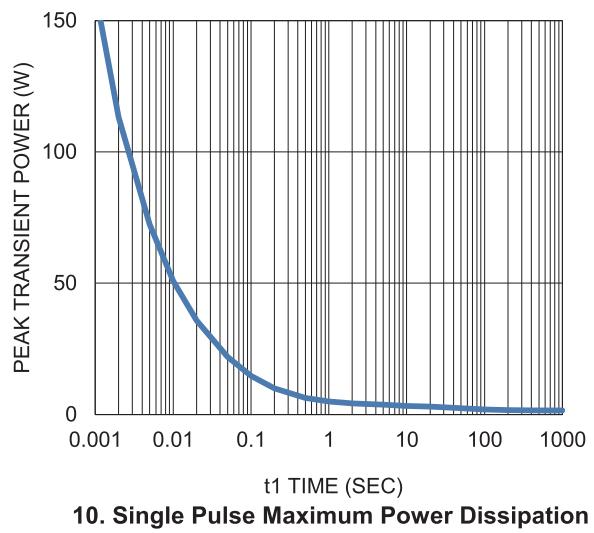
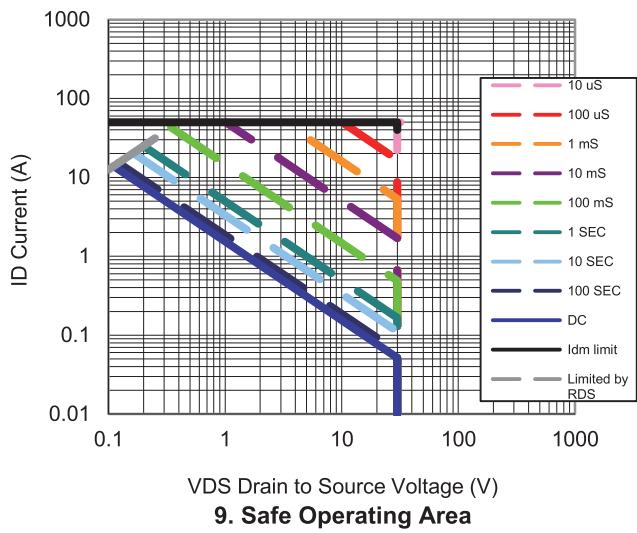
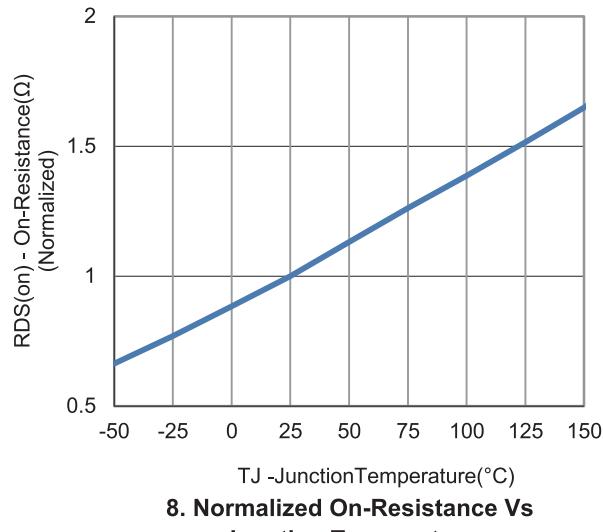
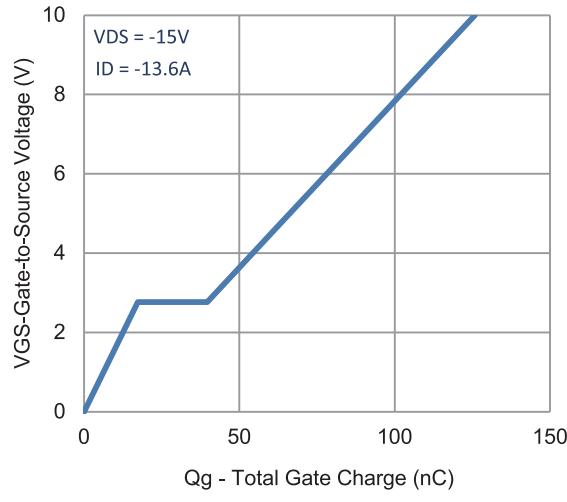


**5. Output Characteristics**

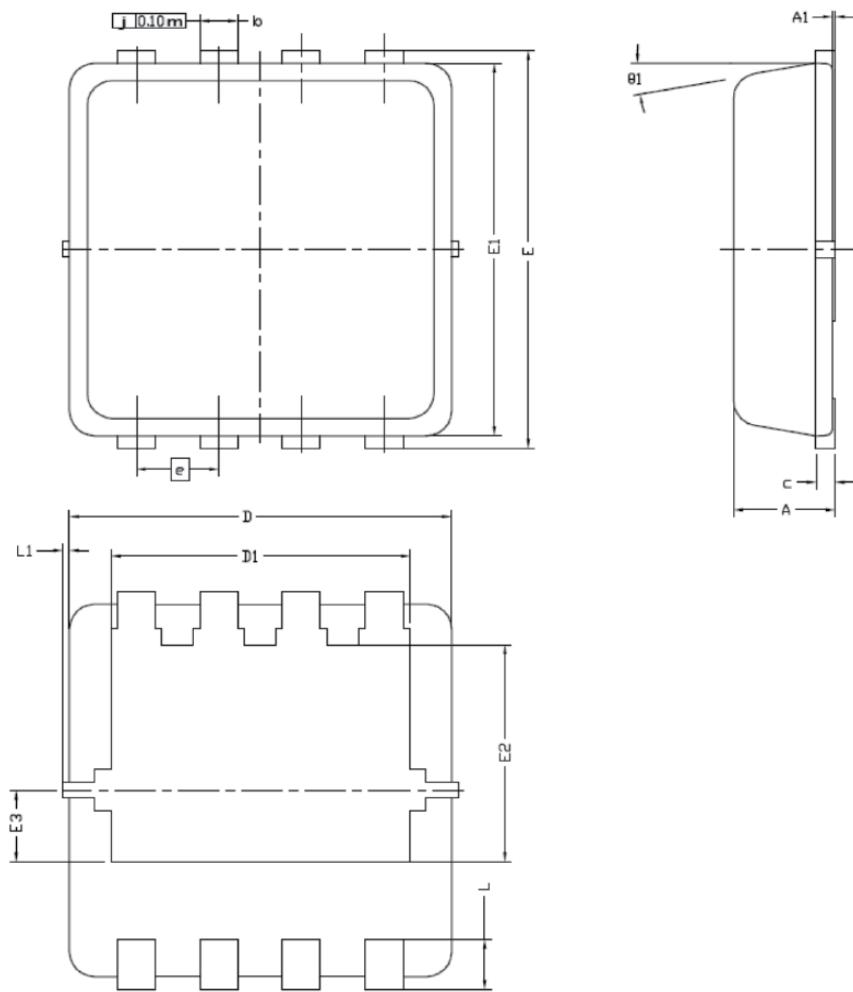


**6. Capacitance**

## Typical Electrical Characteristics



## Package Information



| DIM. | MILLIMETERS |       |       | INCHES    |        |        |
|------|-------------|-------|-------|-----------|--------|--------|
|      | MIN         | NOM   | MAX   | MIN       | NOM    | MAX    |
| A    | 0,700       | 0,80  | 0,900 | 0,0276    | 0,0315 | 0,0354 |
| A1   | 0,00        | ---   | 0,05  | 0,000     | ---    | 0,002  |
| b    | 0,24        | 0,30  | 0,35  | 0,009     | 0,012  | 0,014  |
| c    | 0,10        | 0,152 | 0,25  | 0,004     | 0,006  | 0,010  |
| D    | 3,00 BSC    |       |       | 0,118 BSC |        |        |
| D1   | 2,35 BSC    |       |       | 0,093 BSC |        |        |
| E    | 3,20 BSC    |       |       | 0,126 BSC |        |        |
| E1   | 3,00 BSC    |       |       | 0,118 BSC |        |        |
| E2   | 1,75 BSC    |       |       | 0,069 BSC |        |        |
| E3   | 0,575 BSC   |       |       | 0,023 BSC |        |        |
| e    | 0,65 BSC    |       |       | 0,026 BSC |        |        |
| L    | 0,30        | 0,40  | 0,50  | 0,0118    | 0,0157 | 0,0197 |
| L1   | 0           | ---   | 0,100 | 0         | ---    | 0,004  |
| θ1   | 0°          | 10°   | 12°   | 0°        | 10°    | 12°    |